

Radioactive Ion Beams

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Lecture at the MEDICIS-PROMED Summer School

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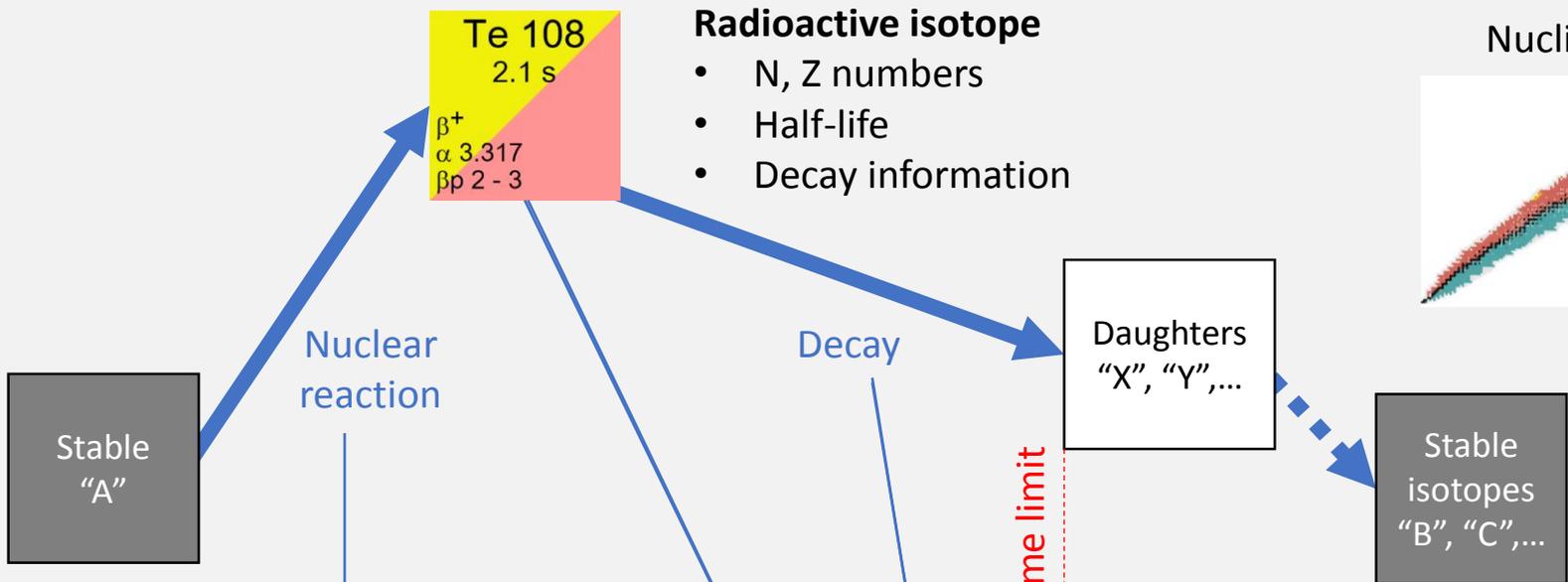
- Context: What – Why - How
- RIB production: full chain
- RIB development

RIB: **R**adioactive **I**on **B**eam!



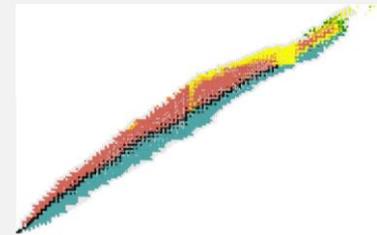
What – Why - How

What



- Radioactive isotope**
- N, Z numbers
 - Half-life
 - Decay information

Nuclide chart



Why

STUDY properties

USE decay products

How



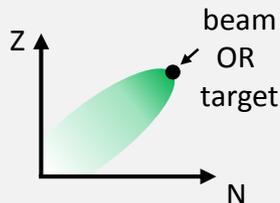
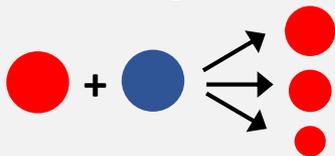
Reactions and Decays

Reaction	$a + {}^{Z+N}\text{X} \rightarrow {}^{Z'+N'}\text{Y} + b$
Notation	${}^{Z+N}\text{X} (a, b) {}^{Z'+N'}\text{Y}$

Main reaction types

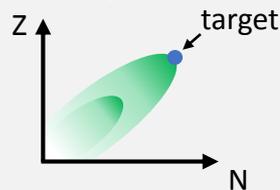
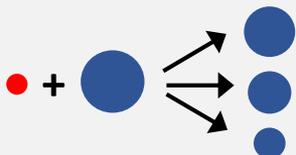
FRAGMENTATION

- Of beam OR of target



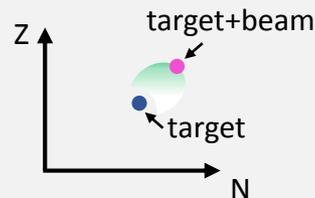
SPALLATION

- 2 channels: spallation-evaporation and spallation-fission
- Accompanied by neutrons (from thermal up to ~10MeV)



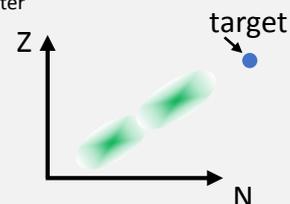
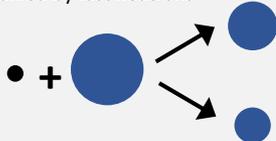
FUSION-EVAPORATION

- Low-energy beams (4-15MeV/A)
- Relatively selective production

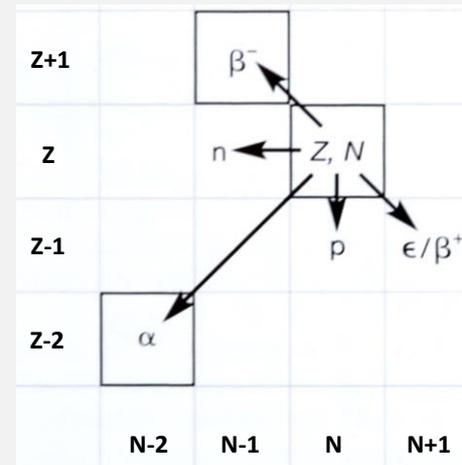


NEUTRON-INDUCED FISSION

- Mostly used for U targets, with neutron converter
- The fission products are neutron-rich
- Accompanied by fast neutrons



Main decay types



α decay

- α: particle energies [MeV]; order: decreasing probability
- γ energies [keV]; order: decreasing intensity

Gd 145 85 s β ⁺ 23.3... β ⁻ 387... γ 329... α 1046...	Gd 146 23.9 m β ⁺ 1750... β ⁻ 1881... γ 1046...	Gd 147 48.3 d β ⁺ 155; 116; 115... β ⁻ 229; 396; 329... α 3183... α 34000	Gd 148 38.1 h β ⁺ 183... β ⁻ 241... γ 197; 121; 678... α 2455
Eu 144 10.2 s β ⁺ 5.2... β ⁻ 1060; 818...	Eu 145 5.93 d β ⁺ 1.7... β ⁻ 894; 1659; 54... α 1.6	Eu 146 4.51 d β ⁺ 2.1... β ⁻ 17; 633; 34... α 280	Eu 147 24.6 d β ⁺ 2.91... β ⁻ 197; 121; 678... α 2455
Sm 143 65 s β ⁺ 2.5... β ⁻ 1027... γ 1815...	Sm 144 8.83 m β ⁺ 1.6	Sm 145 340 d β ⁺ 61; (492...) β ⁻ 280	Sm 146 1.03 · 10 ⁶ a α 2455

Positron emission (β⁺)

- β⁺: Endpoint energies [keV] (cont.spectrum)
- γ energies [keV]; order: decreasing intensity

β⁻ decay

- β⁻: Endpoint energies [keV] (cont.spectrum)
- γ energies [keV]; order: decreasing intensity

Tb 159 100 α 23.2	Tb 160 72.3 d β ⁻ 0.6; 1.7... β ⁺ 679; 299; 965... α 570
Gd 158 24.84	Gd 159 18.48 h β ⁻ 1.0... γ 364; 58...

p decay

Li 4 5.0 MeV 91 · 10 ⁻²⁴ s p	Li 5 1.23 MeV 370 · 10 ⁻²⁴ s p
He 3 0.000134 α 0.00005 t _{1/2, p} 5330	He 4 99.999866

n emission

B 17 5.1 ms β ⁻ β _n ; β _{2n} ; β _{3n} ; β _{4n}	B 18 <26 ns n?
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Radioactive
Isotopes

RIBs

Medicine

- Imaging
- Treatment
- Research

**Fundamental &
Applied Sciences**

- Nuclear physics
- Atomic physics
- Solid state physics
- Materials science
- Life sciences

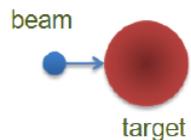
Half-life



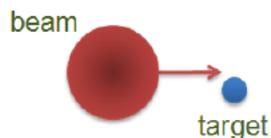
Industry

- Flow tracing
- Mixing measurements
- Neutron imaging
- Gamma sterilization

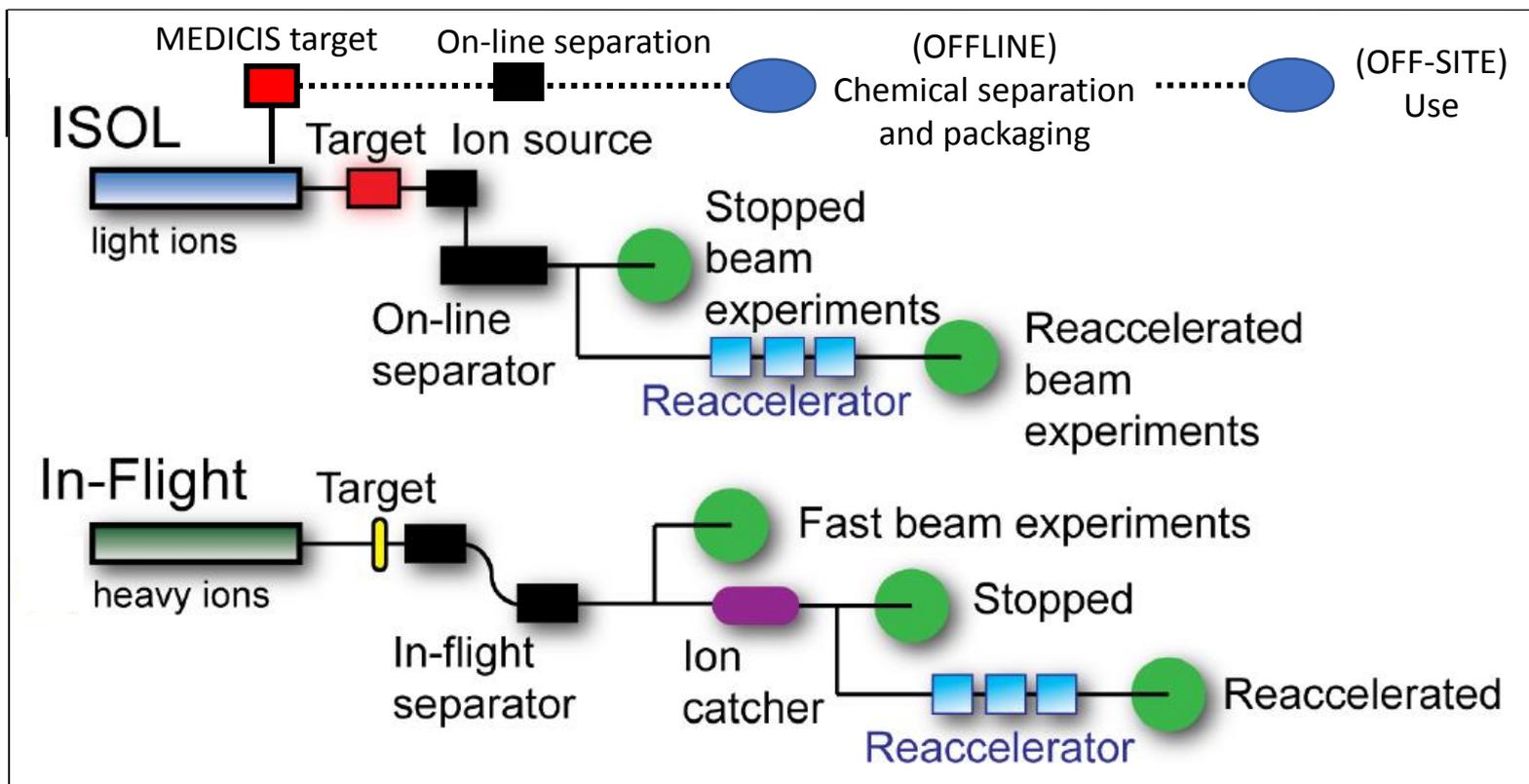
RIB production methods



- ✓ Spallation
- ✓ Fragmentation
- ✓ Fission



- ✓ Fragmentation
- ✓ Fusion-evaporation

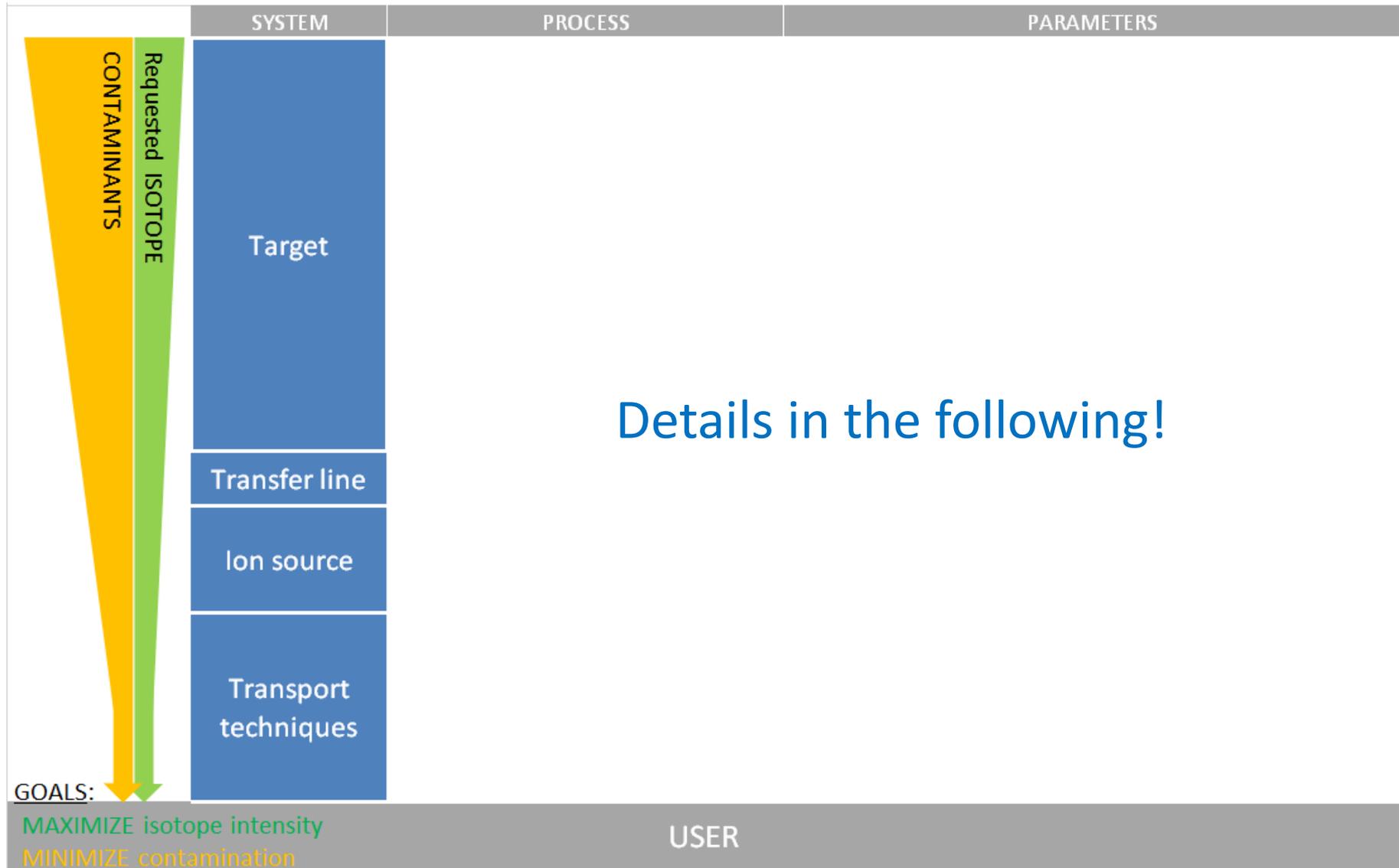


COMPARISON	ISOL	In-Flight
Projectile	light	heavy
Target	thick	thin
Release from target	slow	fast
RIB intensity	high	low
RIB quality	good	poor
RIB energy	low	high

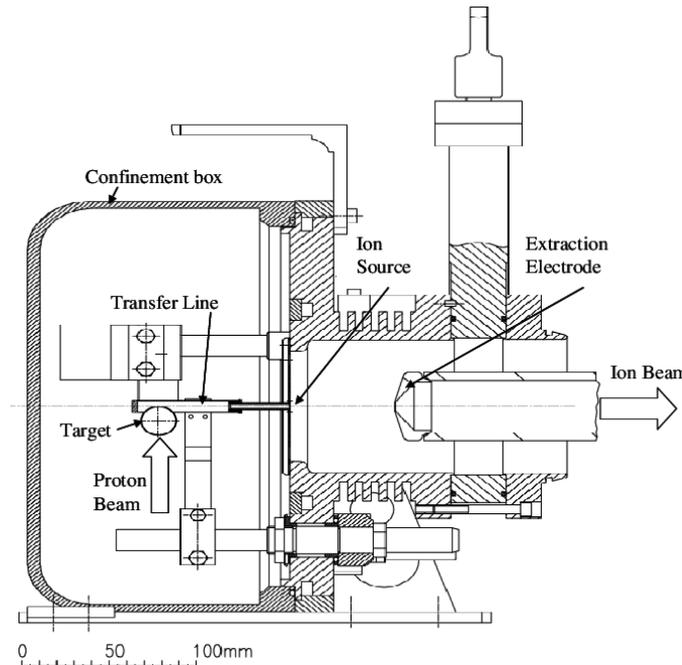
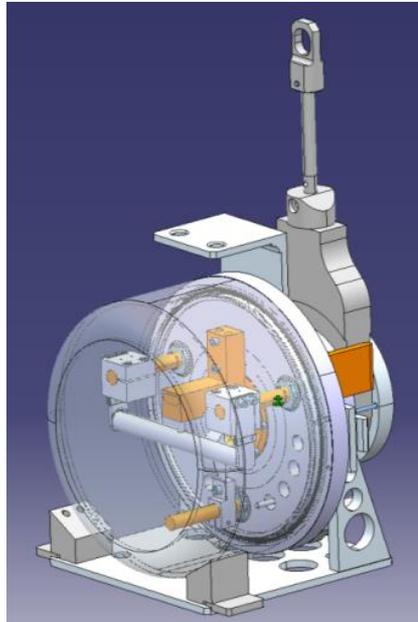
O.Tarasov

M. Kowalska

ISOL – method overview



ISOLDE target



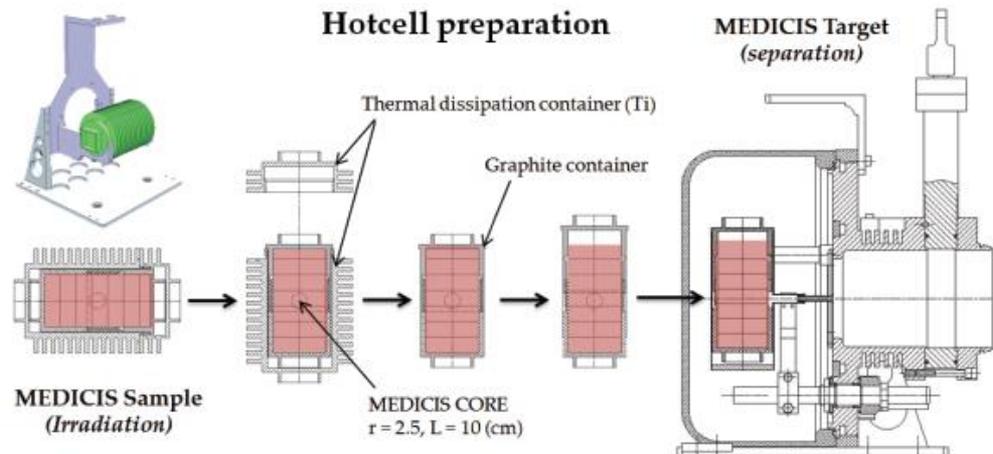
Target types:

- Solid metals
- Oxides
- Carbides
- Molten materials

MEDICIS target

Beam scattered by primary target, so:

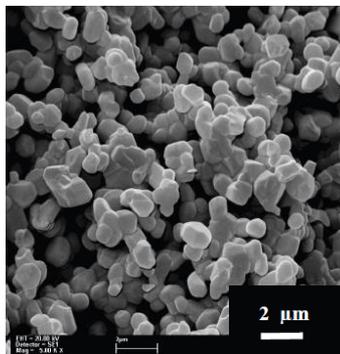
- Volume increase (4x ISOLDE target)
- Density increase



Targets

SYSTEM	PROCESS	PARAMETERS
Target	Manufacturing	Target type, composition, density and dimensions
		Particle radius; open porosity
		Melting point; phase diagrams
	Isotope production	Reaction type; cross section
		Particle conversion (p -> n; e ->γ)
	Chemistry	Chemical compatibility; temperature stability
	Calorimetry / heat management	Molecular sideband
Deposited power; heat transfer; thermal stability		
Diffusion	Thermal conductivity, emissivity; cooling	
	Arrhenius parameters; temperature	
	Radiation-enhanced diffusion	
Ageing	Shockwave effects (pulsed beam)	
	Target sintering; grain growth; radiation damage	
		Acumulated dose

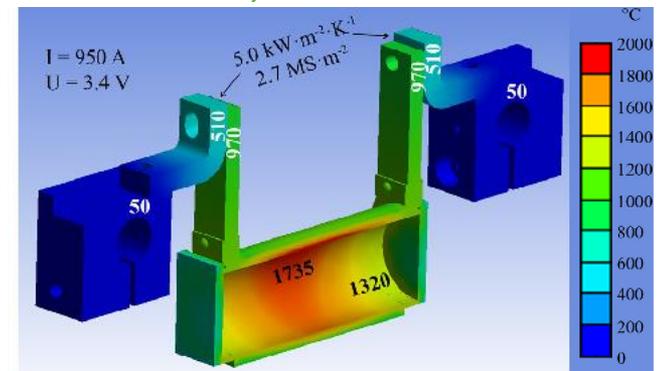
Al_2O_3 - SEM



Nanometric CaO powder

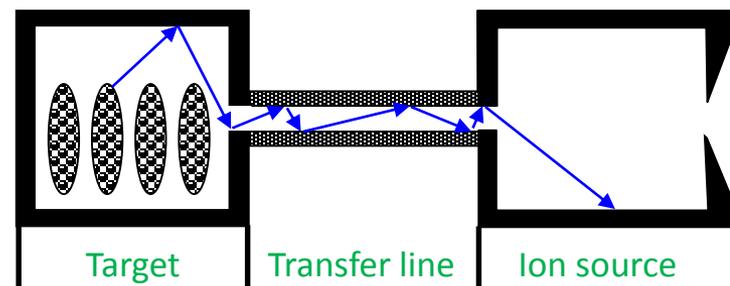
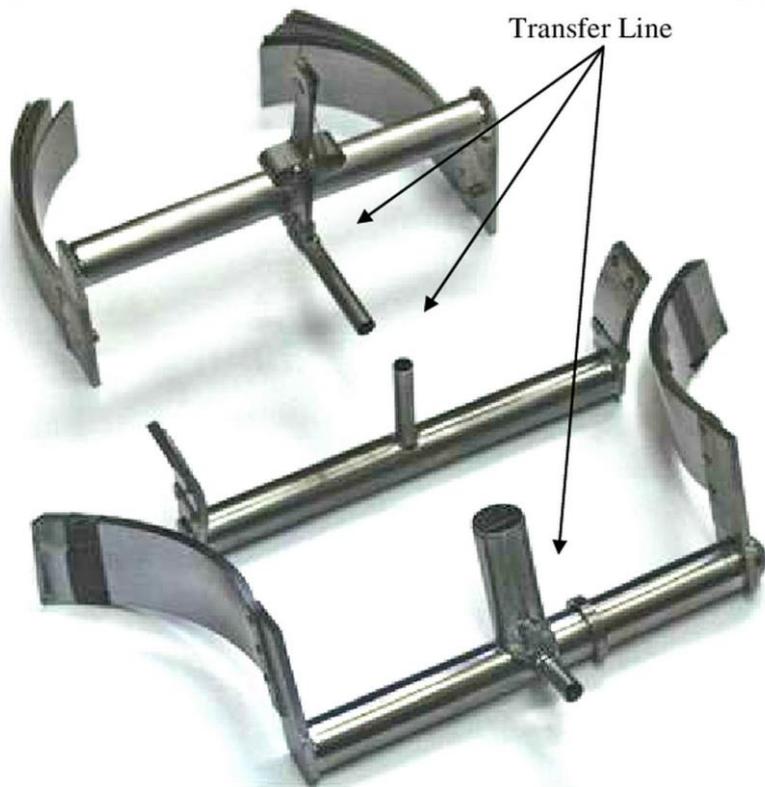


Thermal analysis

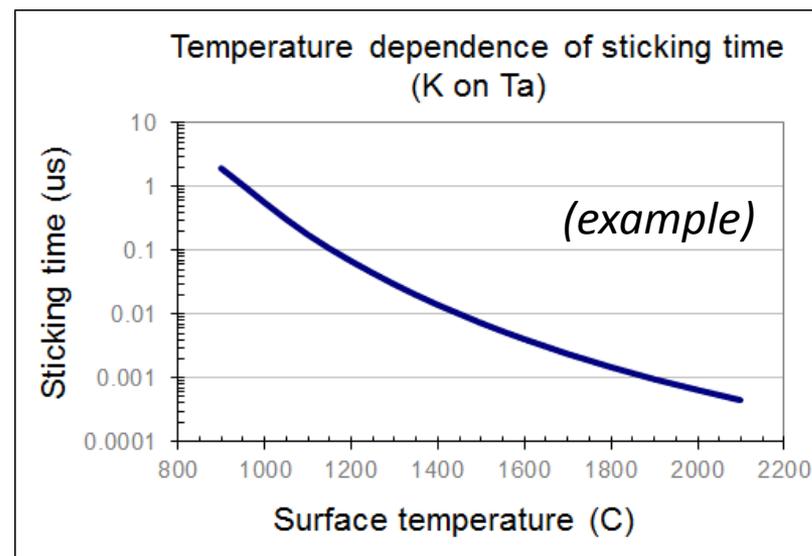


Transfer lines

SYSTEM	PROCESS	PARAMETERS
Transfer line	Effusion	Adsorption enthalpy; sticking time Number of wall collisions; flight time



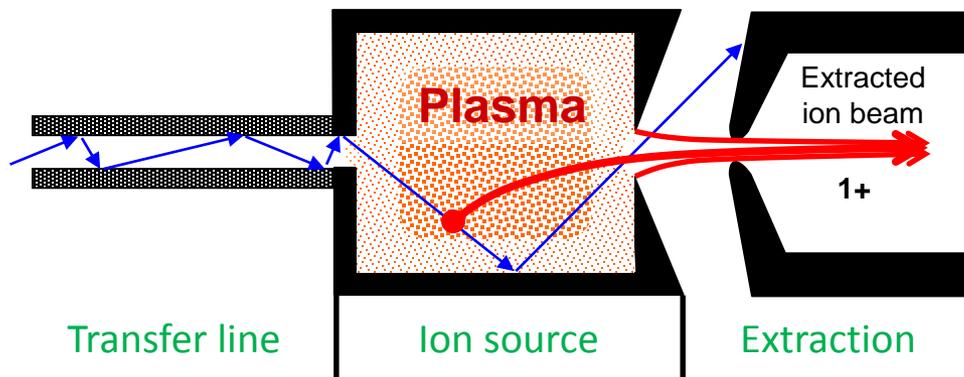
GOALS: fast, selective, (efficient)



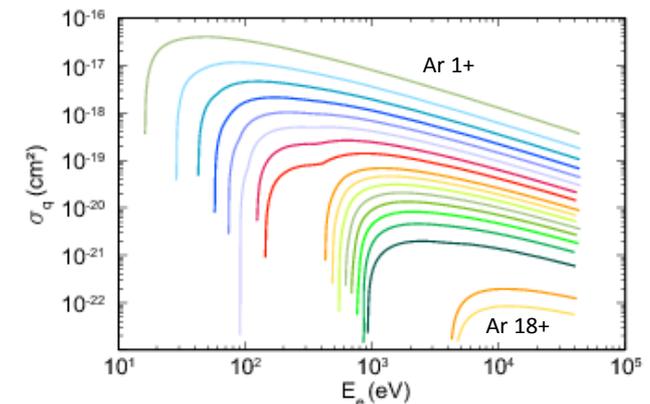
SYSTEM	PROCESS	PARAMETERS
Ion source	Ionization	Ionization mechanism; cross sections; confinement; recombination
	Neutral flow	Gas pumping; material evaporation; support gas
	Extraction	Electrical field; magnetical field; space charge; emittance

Ion source types

1+	1+ → N+
<ul style="list-style-type: none"> ➤ Surface ionization ➤ Laser ionization (e.g. RILIS) ➤ Electron beam impact ionization (e.g. VADIS) ➤ RF heated plasma sources (e.g ECR, Helicon, COMIC) 	<ul style="list-style-type: none"> ➤ EBIS (electron beam ion source) ➤ ECR (electron cyclotron resonance)
GOALS: efficient, selective, (fast)	GOALS: efficient, (fast)



Example: Argon ionization cross sections (stepwise)



Transport techniques

GOALS:

- RIB characterization
- Selectivity
- Accumulation
- Preparation (energy, size)
- Efficiency

Isobaric contamination

	O 12 580 keV $7.9 \cdot 10^{-22}$ s	O 13 8.58 ms	O 14 70.59 s	O 15 2.03 m	O 16 99.757
N 10 2.3 MeV $200 \cdot 10^{-24}$ s	N 11 -0.77 MeV $-590 \cdot 10^{-21}$ s	N 12 11.0 ms	N 13 9.96 m	N 14 99.636	N 15 0.364
C 9 126.5 ms	C 10 19.3 s	C 11 20.38 m	C 12 98.93	C 13 1.07	C 14 5730 a
B 8 770 ms	B 9 0.54 keV $800 \cdot 10^{-21}$ s	B 10 19.9	B 11 80.1	B 12 20.20 ms	B 13 17.33 ms
Be 7 53.29 d	Be 8 6.8 eV $67 \cdot 10^{-18}$ s	Be 9 100	Be 10 $1.6 \cdot 10^8$ a	Be 11 13.8 s	Be 12 23.6 ms
Li 6 7.59	Li 7 92.41	Li 8 840.3 ms	Li 9 178.3 ms	Li 10 230 keV $2.0 \cdot 10^{-21}$ s	Li 11 8.5 ms

INPUT

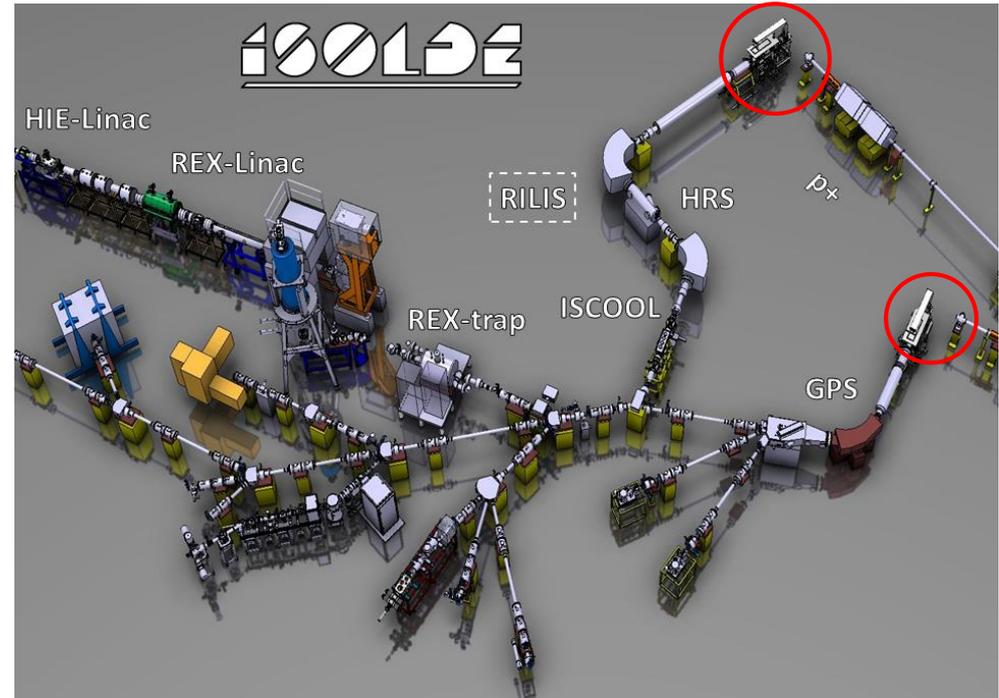
1+ ions, low energy (≤ 60 keV)/u
Isobaric contaminants
Energy and angular spread

Transport techniques

OUTPUT

Yield specification
Purity specification
Delivery specification (time structure,
energy, charge state, size)

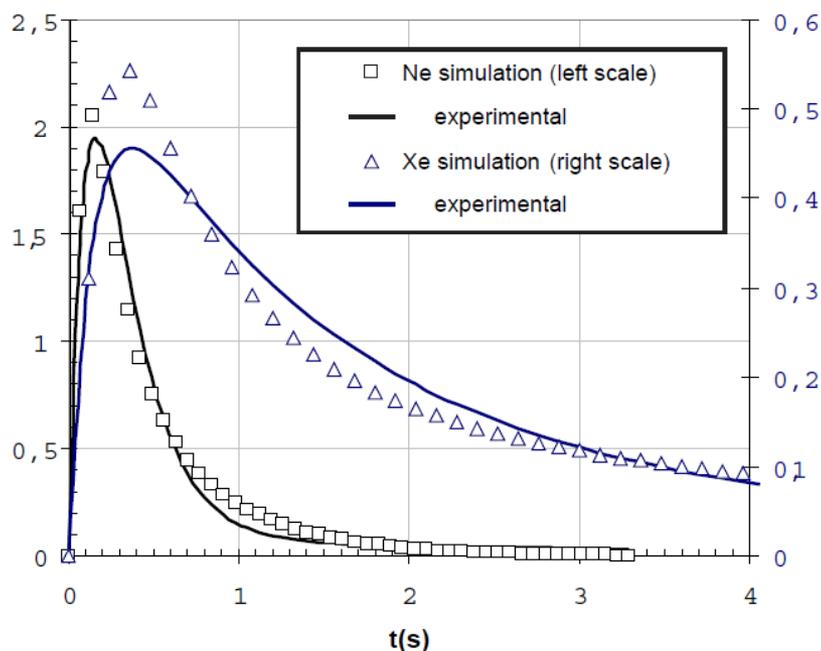
Example: ISOLDE facility



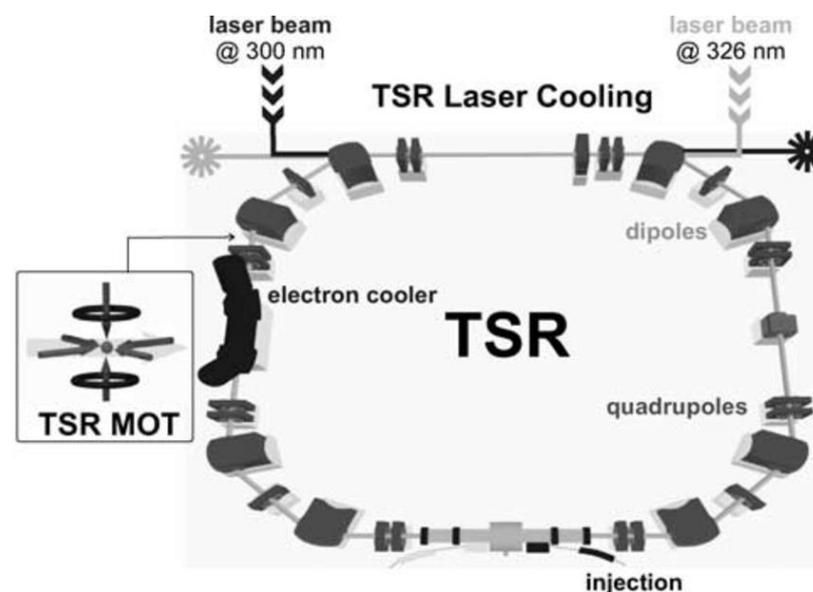
Transport techniques

SYSTEM	PROCESS	PARAMETERS
Transport techniques	High-resolution separator (e.g. HRS)	Mass resolution
	Gating for release curve (slow)	Release curves (comparative)
	Gating for ion source (fast, e.g. RILIS)	Selective ionization; extraction curves
	Selective accumulation (e.g. ISOLTRAP)	Space charge limit; accumulation time; extraction time; efficiency
	Post-acceleration (e.g. REX-ISOLDE)	Energy; efficiency (N+)
	Storage ring (e.g. TSR)	Injection efficiency

Example: comparative release curves



Example: storage ring for accumulation and cooling

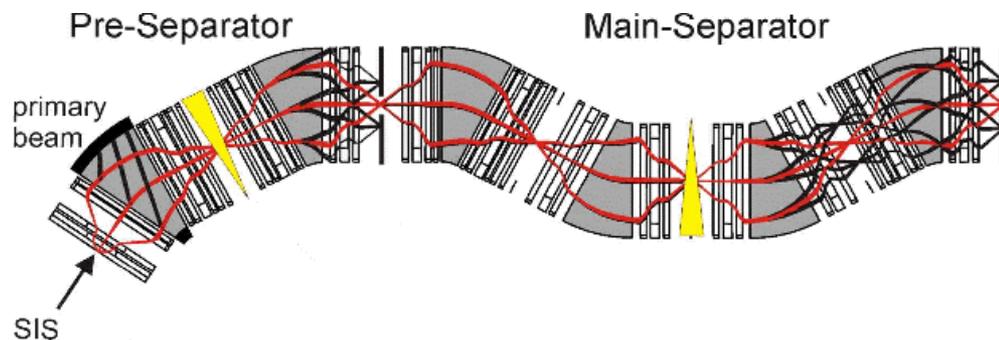
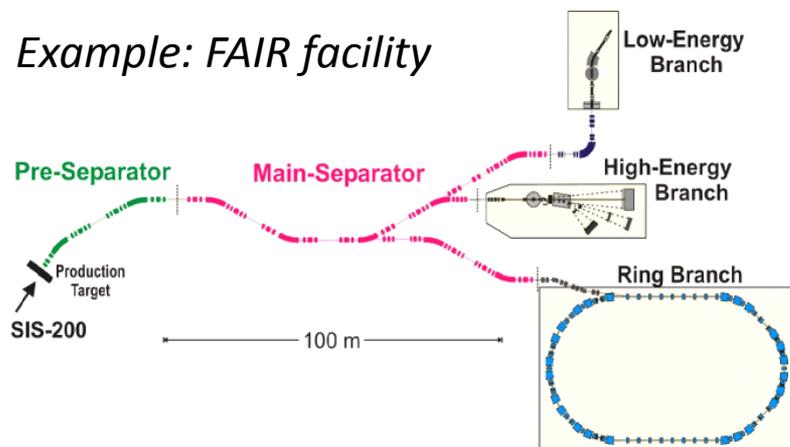


ISOL – method overview

	SYSTEM	PROCESS	PARAMETERS	
 <p>CONTAMINANTS</p> <p>Requested ISOTOPE</p>	Target	Manufacturing	Target type, composition, density and dimensions Particle radius; open porosity Melting point; phase diagrams	
		Isotope production	Reaction type; cross section Particle conversion ($p \rightarrow n$; $e \rightarrow \gamma$)	
		Chemistry	Chemical compatibility; temperature stability Molecular sideband	
		Calorimetry / heat management	Deposited power; heat transfer; thermal stability Thermal conductivity, emissivity; cooling	
		Diffusion	Arrhenius parameters; temperature Radiation-enhanced diffusion Shockwave effects (pulsed beam)	
		Ageing	Target sintering; grain growth; radiation damage Acumulated dose	
		Transfer line	Effusion	Adsorption enthalpy; sticking time Number of wall collisions; flight time
	Ion source	Ionization	Ionization mechanism; cross sections; confinement; recombination	
		Neutral flow	Gas pumping; material evaporation; support gas	
		Extraction	Electrical field; magnetical field; space charge; emittance	
	Transport techniques	High-resolution separator (e.g. HRS)	Mass difference	
		Gating for release curve (slow)	Release curves (comparative)	
		Gating for ion source (fast, e.g. RILIS)	Selective ionization; extraction curves	
		Selective accumulation (e.g. ISOLTRAP)	Space charge limit; accumulation time; extraction time	
		Post-acceleration (e.g. REX-ISOLDE)	Energy; efficiency (N^+)	
		Storage ring (e.g. TSR)	Injection efficiency	
	<p>GOALS:</p> <p>MAXIMIZE isotope intensity</p> <p>MINIMIZE contamination</p>	USER		

In-Flight method overview

Example: FAIR facility



SYSTEM	PROCESS	PARAMETERS
Beam	Production	Element, energy, intensity
	Delivery	Size, shape, time structure
Target	Manufacturing	Target type, composition, density and dimensions Melting point; phase diagrams
	Isotope production	Reaction type; cross section Particle conversion ($p \rightarrow n$)
	Calorimetry / heat management	Deposited power; heat transfer; thermal stability
		Thermal conductivity, emissivity; cooling Rotation/circulation speed
	Ageing	Accumulated dose
Transport techniques	High-resolution separator (including dipoles, degraders and Wien filters)	Mass and energy resolution
	Ion catcher (=compact TIS unit)	Parameters of diffusion + effusion + ionization + extraction
	Beam cooling	Space charge limit; cooling time; bunch width; transmission
	Selective accumulation	Space charge limit; accumulation time; extraction time; efficiency
	Post-acceleration	Energy; efficiency (N^+)
	Storage ring	Injection efficiency

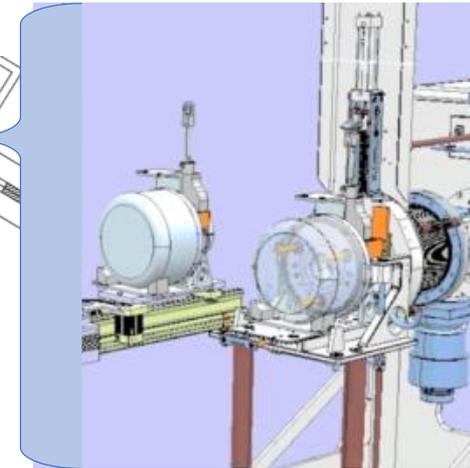
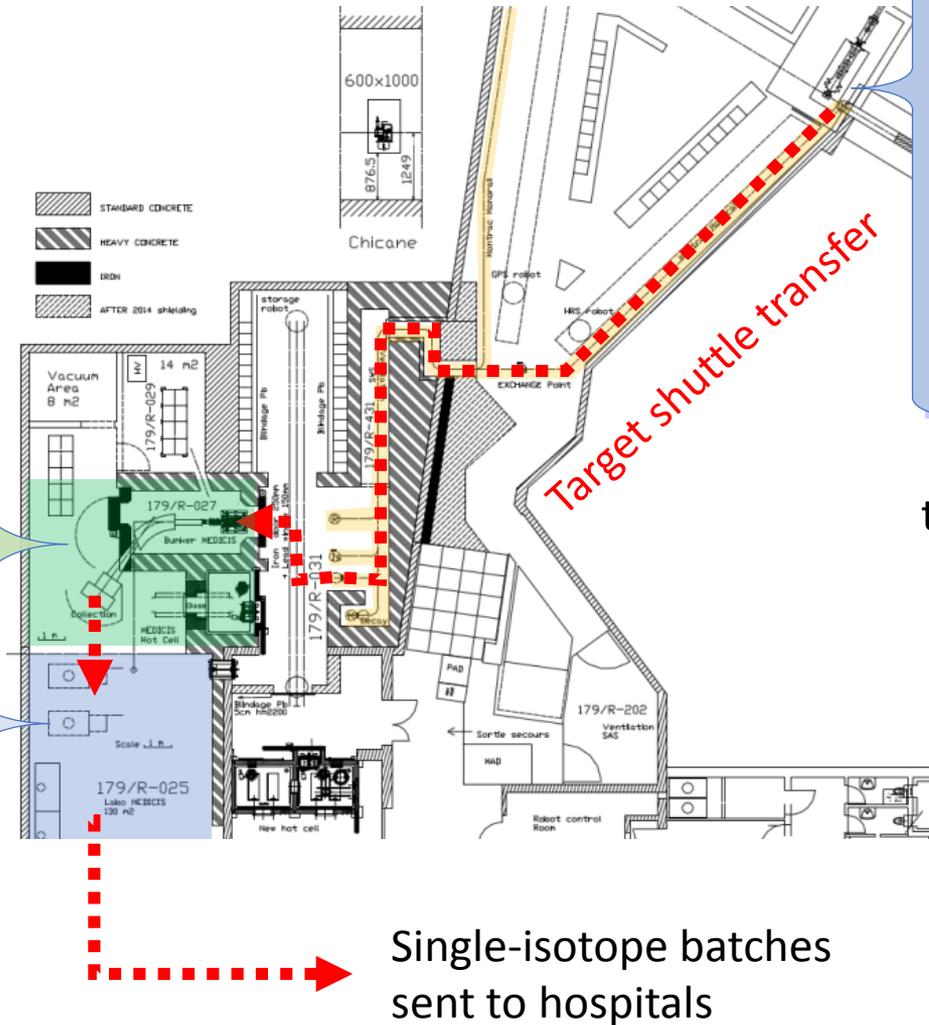
MEDICIS – method overview

MASS SEPARATOR

- Isobaric selection
- Products implanted on: metallic foils, polymeric supports with salt layers, or ice samples.

CHEMICAL LAB

- Chemical purification (cation-exchange chromatography)



MEDICIS target unit

Single-isotope batches sent to hospitals

Production of medical isotopes

SYSTEM	PROCESS	PARAMETERS
Beam	Choice of driver	Large accelerator (e.g. ISOLDE MEDICIS), cyclotron*, nuclear reactor
	Production	Particle, energy, intensity
	Delivery	Size, shape, time structure
Target	Manufacturing	Target type, composition, density and dimensions
		Grain size; open porosity
		Melting point; phase diagrams
	Isotope production	Reaction type; cross section
		Particle conversion rate ($p \rightarrow n$; $e \rightarrow \gamma$)
	Chemistry	Chemical compatibility; temperature stability
		Molecular sideband
	Calorimetry / heat management	Deposited power; heat transfer; thermal stability
Thermal conductivity, emissivity; cooling		
Diffusion	Arrhenius parameters; temperature	
	Radiation-enhanced diffusion	
	Shockwave effects (pulsed beam)	
Ageing	Target sintering; grain growth; radiation damage	
	Accumulated dose	
Transfer line	Effusion	Adsorption enthalpy; sticking time Number of wall collisions; flight time
Ion source	Ionization	Ionization mechanism; cross sections; confinement; recombination
	Neutral flow	Gas pumping; material evaporation; support gas
	Extraction	Electrical field; magnetical field; space charge; emittance
Transport techniques	Mass separation	Mass resolution
	▶ Sample implantation/irradiation	Sample type; amount of contaminants; implantation time
	Chemical purification	Resin type, eluent type
	Radiopharmaceutical synthesis	Bioconjugate type, chelator type

If driver=cyclotron
jump directly here

PROCEDURES



Preparation of:

- Components
- Systems

Verifications:

- Parameters
- Full performance

DEVELOPMENT of a new RIB

Development CATEGORIES

C 9 126.5 ms β^+ 15.5... β^- 8.24; 10.92... β_{α}	C 10 19.3 s β^+ 1.9... γ 718; 1022	C 11 20.38 m β^+ 1.0 no γ	C 12 98.93 ϵ 0.0035	C 13 1.07 ϵ 0.0014	C 14 5730 a β^- 0.2 no γ	C 15 2.45 s β^- 4.5; 9.8... γ 5298...	C 16 0.747 s β^- 4.7; 7.9... β_n 0.79; 1.72	C 17 193 ms β^- β_n 1.62... γ 1375; 1849; 1906...
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1

2

- 1) ISOTOPE already produced
- 2) ELEMENT already produced
- 3) ELEMENT not produced

5 B	6 C	7 N
13 Al	14 Si	15 P

3

LIMITATION analysis

- a) Higher INTENSITY required?
- b) FASTER production required?
- c) Higher PURITY required?
- d) Higher RELIABILITY required?
- e) Apply technology from OTHER FACILITY?
- f) NEW TECHNOLOGY required?

Choice of BASELINE

QA of existing knowledge

Isotope	Half life	Yield (at/ μ C)	Target	Driver
C 9	126.5 ms	2.0E+03	CaO	PSB
C 9	126.5 ms	4.0E+02	CaO	PSB

(example)

Stability?

Reproducibility?

Knowledge of all parameters?

Modeling status?

CONSOLIDATION activities

IMPLEMENTATION and TESTS

- Validation of PHENOMENA and PARAMETERS
- Model BENCHMARKING for used range
- Refine the ENGINEERING solutions
- Manufacturing and control PROCESSES
- Dedicated tests of EXISTING SYSTEMS
- Tests of NEW COMPONENTS (separated)
- INTEGRATION tests
- Tests of COMPLETE LAYOUT (integrated): offline characterization, RIB production

"Knowledge matrix"

				new
		new		

You are the experts!

- Discussion on specific examples
- Missing parameters?
- Observed limitations
- Side results and possible applications
- Follow-up interests